

# GBU8005 - GBU810

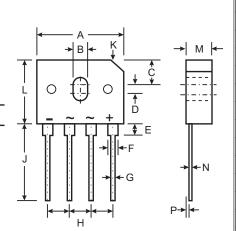
### 8.0A GLASS PASSIVATED BRIDGE RECTIFIER

### **Features**

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1500VRMS
- Low Reverse Leakage Current
- Surge Overload Rating to 200A Peak
- Ideal for Printed Circuit Board Applications
- **UL Listed Under Recognized Component** Index, File Number E94661
- Lead Free Finish, RoHS Compliant (Note 4)

### **Mechanical Data**

- Case: GBU
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 (e3)
- Polarity: Marked on Body
- Mounting: Through Hole for #6 Screw
- Mounting Torque: 5.0 Inch-pounds Maximum
- Ordering Information: See Last Page
- Marking: Date Code and Type Number
- Weight: 6.6 grams (approximate)



GBU					
Dim	Min	Max			
Α	21.8	22.3			
В	3.5	4.1			
С	7.4	7.9			
D	1.65	2.16			
Е	2.25	2.75			
F	1.95	2.35			
G	1.02	1.27			
Н	4.83	5.33			
J	17.5	18.0			
K	3.2 X 45°				
L	18.3	18.8			
M	3.30	3.56			
N	0.46	0.56			
Р	0.76	1.0			
All Dimensions in mm					

#### **Maximum Ratings and Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

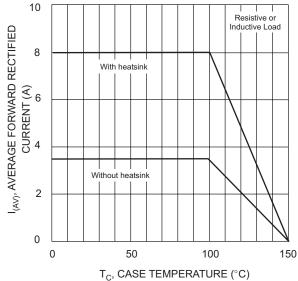
Single phase, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	GBU 8005	GBU 801	GBU 802	GBU 804	GBU 806	GBU 808	GBU 810	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Forward Rectified Current (Note 1) @ T <sub>C</sub> = 100°C	I <sub>(AV)</sub>	8.0						Α	
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load		200					Α		
Forward Voltage (per element) @ I <sub>F</sub> = 4.0A	V <sub>FM</sub>				1.0				V
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		5.0 500					μА		
I <sup>2</sup> t Rating for Fusing (t < 8.3ms) (Note 2)		166					A <sup>2</sup> s		
Typical Total Capacitance per Element (Note 3)		130					pF		
Typical Thermal Resistance Junction to Case (Note 1)		2.2				°C/W			
Operating and Storage Temperature Range		-55 to +150				°C			

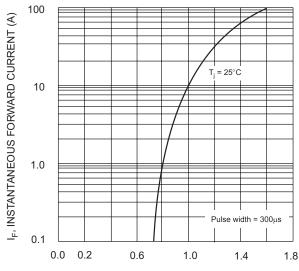
Notes:

- 1. Unit mounted on 50 x 50 x 1.6mm copper plate heatsink.
- 2. Non-repetitive, for t > 1.0ms and < 8.3ms.
- 3. Per element, measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 4. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.

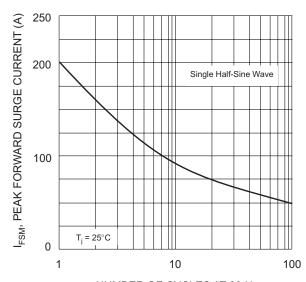




I<sub>C</sub>, CASE TEMPERATURE (°C)
Fig. 1 Forward Current Derating Curve



 $\rm V_F$ , INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics, per element



NUMBER OF CYCLES AT 60 Hz
Fig. 3 Maximum Non-Repetitive Surge Current

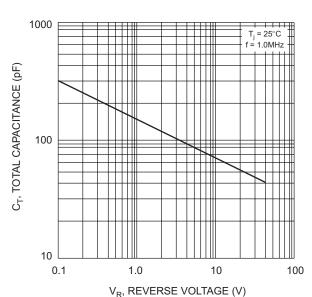


Fig. 4 Typical Total Capacitance, per element

## Ordering Information (Note 5)

Device	Packaging	Shipping		
GBU8005	GBU	20/Tube		
GBU801	GBU	20/Tube		
GBU802	GBU	20/Tube		
GBU804	GBU	20/Tube		
GBU806	GBU	20/Tube		
GBU808	GBU	20/Tube		
GBU810	GBU	20/Tube		

Notes: 5. For packaging details, visit our website at http://www.diodes.com/datasheets/ap02008.pdf.



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